# NSN 5962-01-177-1369

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# Body Length:

1.290 inches

# Body Width:

Between 0.500 inches and 0.610 inches

# **Body Height:**

0.210 inches

#### **Maximum Power Dissipation Rating:**

1.4 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

Radar system an/fps-117

#### **Features Provided:**

Bipolar and programmable and schottky and monolithic

#### Inclosure Material:

Ceramic

# Inclosure Configuration:

Dual-in-line

#### Output Logic Form:

Transistor-transistor logic

#### Input Circuit Pattern:

14 input

#### Case Outline Source And Designator:

D-3 mil-m-38510

#### **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

#### Memory Device Type:

Rom

# **Test Data Document:**

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

#### Unit Of Measure:

Demilitarization:

Yes - demil/mli

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